

## High Voltage 3-Phase Motor Driver

### Features and Benefits

- Built-in pre-drive IC
- IGBT power element
- CMOS compatible input (3.3 to 5 V)
- High-side gate driver using bootstrap circuit or floating power supply
- Integrated Fast Recovery Diode (FRD) as freewheeling diode for each IGBT
- Built-in protection circuit for controlling power supply voltage drop
- Built-in overtemperature detection circuit (TD)
- 3-shunt configuration
- Output of fault signal during operation of protection circuit
- Output current 3 A
- Small SIP (SLA 24-pin)

### Package: Power SIP



Not to scale

### Description

The SLA6845MZ inverter power module (IPM) device provides a robust, highly-integrated solution for optimally controlling 3-phase motor power inverter systems and variable speed control systems used in energy-conserving designs to drive motors of residential and commercial appliances. These ICs take 230 VAC input voltage, and 3 A (continuous) output current. They can withstand voltages of up to 600 V (IGBT breakdown voltage).

The SLA6840M power package includes an IC with all of the necessary power elements (six IGBTs), pre-driver ICs (two), and freewheeling diodes (six), needed to configure the main circuit of an inverter. This enables the main circuit of the inverter to be configured with fewer external components than traditional designs.

Applications include residential white goods (home applications) and commercial appliance motor control:

- Air conditioner fan
- Refrigerator compressor
- Dishwasher pump

### Functional Block Diagram

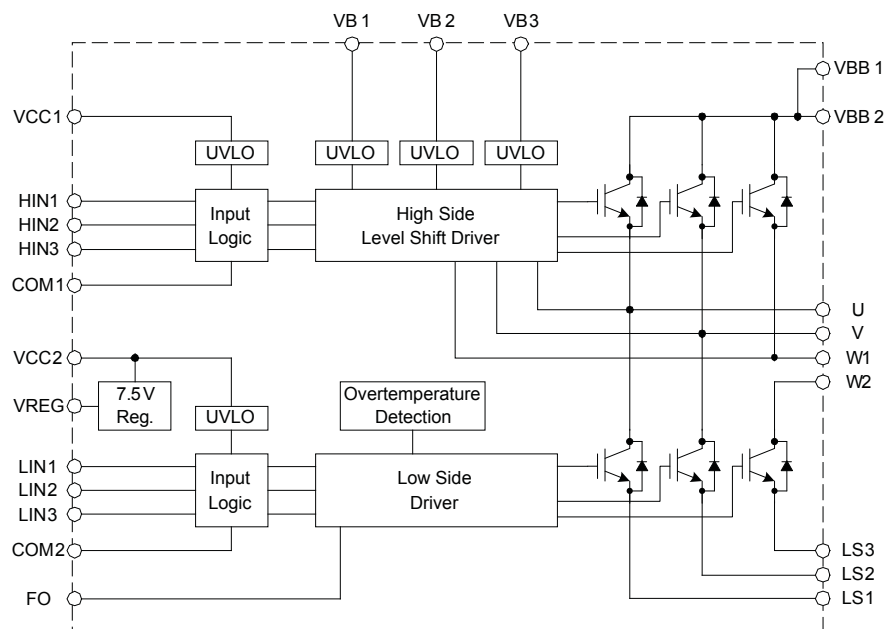


Figure 1. Driver block diagram.

## Selection Guide

| Part Number | Packing            | IGBT Breakdown Voltage, $V_{CES(min)}$ (V) | IGBT Saturation Voltage, $V_{CE(sat)}(typ)$ (V) | Output Current             |                           |
|-------------|--------------------|--------------------------------------------|-------------------------------------------------|----------------------------|---------------------------|
|             |                    |                                            |                                                 | Continuous, $I_O(max)$ (A) | Pulsed, $I_{OP}(max)$ (A) |
| SLA6845MZ   | 18 pieces per tube | 600                                        | 1.75                                            | 3                          | 6                         |

Absolute Maximum Ratings, valid at  $T_A = 25^\circ\text{C}$ 

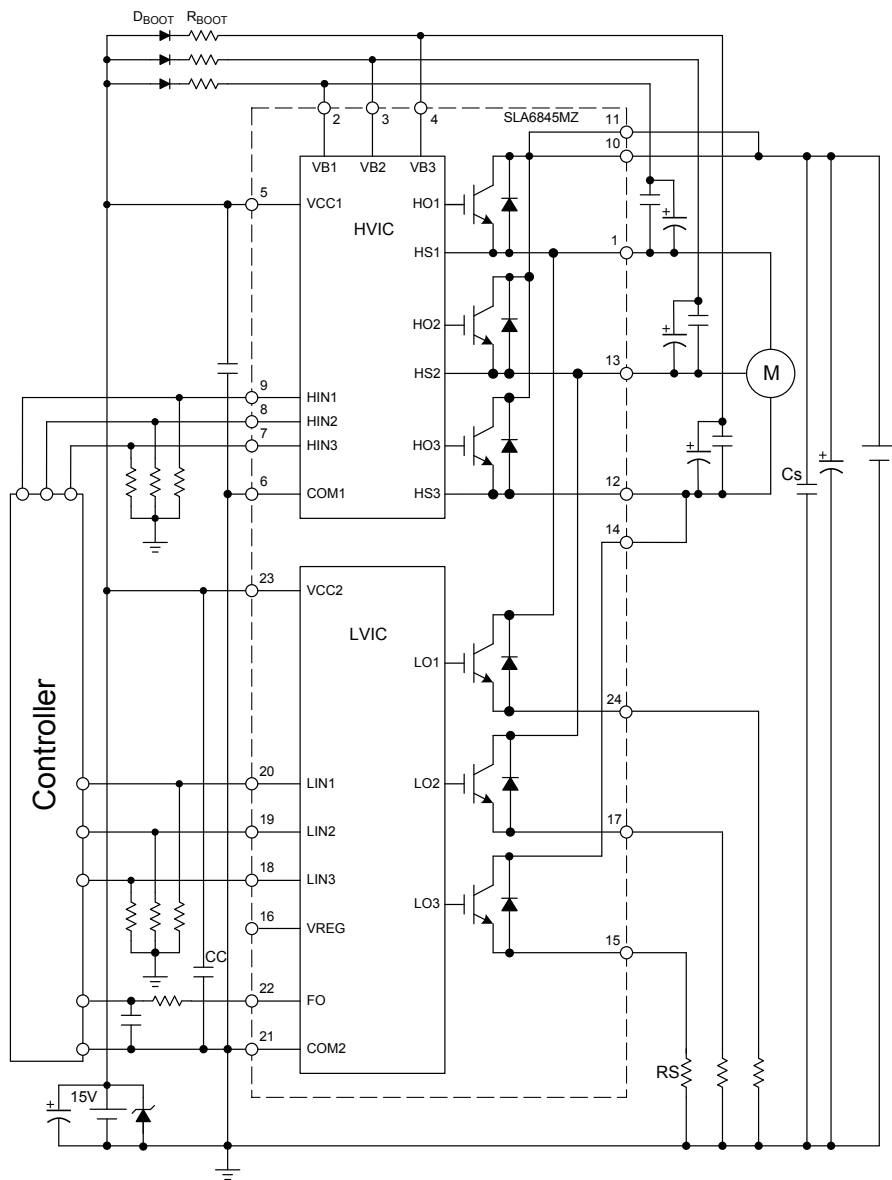
| Characteristic                           | Symbol             | Remarks                                                                                                                                                                                                          | Rating     | Unit               |
|------------------------------------------|--------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|--------------------|
| Main Supply Voltage                      | $V_{BB}$           | Maximum voltage that can be applied between $V_{BB}$ and $LSx$ continuously                                                                                                                                      | 450        | V                  |
| Main Supply Voltage (Peak)               | $V_{BB(surge)}$    | Maximum voltage allowed between $V_{BB}$ and $LSx$ , including transient switching noise. If surge voltages reach this rating, the snubber circuit should be improved so the voltage does not exceed this level. | 500        | V                  |
| IGBT Breakdown Voltage                   | $V_{CES}$          |                                                                                                                                                                                                                  | 600        | V                  |
| Logic Supply Voltage                     | $V_{CC}$           | Between $V_{CC}$ and COM                                                                                                                                                                                         | 20         | V                  |
| Bootstrap Voltage                        | $V_{BS}$           | Between $VB$ and $HS$ (U, V, and W phases)                                                                                                                                                                       | 20         | V                  |
| Output Current, Continuous               | $I_O$              | $T_C = 25^\circ\text{C}$                                                                                                                                                                                         | 3          | A                  |
| Output Current, Pulsed                   | $I_{OP}$           | $PW \leq 100 \mu\text{s}$                                                                                                                                                                                        | 6          | A                  |
| Output Current for Regulator             | $I_{REG}$          |                                                                                                                                                                                                                  | 35         | mA                 |
| Input Voltage                            | $V_{IN}$           |                                                                                                                                                                                                                  | -0.5 to 7  | V                  |
| Allowable Power Dissipation              | $P_D$              | $T_C = 25^\circ\text{C}$ , all elements operating                                                                                                                                                                | 32         | W                  |
| Thermal Resistance (Junction to Case)    | $R_{\theta JC(I)}$ | All elements operating (IGBT)                                                                                                                                                                                    | 3.8        | $^\circ\text{C/W}$ |
|                                          | $R_{\theta JC(F)}$ | All elements operating (FRD)                                                                                                                                                                                     | 4.2        | $^\circ\text{C/W}$ |
| Thermal Resistance (Junction to Ambient) | $R_{\theta JA}$    | All elements operating (IGBT and FRD)                                                                                                                                                                            | 25         | $^\circ\text{C/W}$ |
| Case Operating Temperature               | $T_{COP}$          |                                                                                                                                                                                                                  | -20 to 100 | $^\circ\text{C}$   |
| Junction Temperature (IGBT)              | $T_J$              |                                                                                                                                                                                                                  | 150        | $^\circ\text{C}$   |
| Storage Temperature                      | $T_{stg}$          |                                                                                                                                                                                                                  | -40 to 150 | $^\circ\text{C}$   |

## Recommended Operating Conditions

| Characteristic                             | Symbol     | Remarks                                                                                                                                                                                       | Min. | Typ. | Max. | Units            |
|--------------------------------------------|------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|------------------|
| Main Supply Voltage                        | $V_{BB}$   | Between $V_{BB}$ and $LS$ , $I_{BB} \leq 2 \text{ A}$                                                                                                                                         | –    | 300  | 450  | V                |
| Logic Supply Voltage                       | $V_{CC}$   | Between $V_{CC}$ and COM                                                                                                                                                                      | 13.5 | –    | 16.5 | V                |
| Shunt Resistor                             | $R_S$      | $LS1$ , $LS2$ , $LS3$ to COM2                                                                                                                                                                 | 0.3  | –    | –    | $\Omega$         |
| Dead Time                                  | $t_{dead}$ | Between $LS1$ , $LS2$ , $LS3$ and COM                                                                                                                                                         | 1.5  | –    | –    | $\mu\text{s}$    |
| Overcurrent Protection (OCP) Response Time | $t_{OCP}$  | No built-in OCP. If OCP required, implement using an external circuit. Measure $t_{OCP}$ from overcurrent occurrence to shutdown command received on corresponding $HINx$ or $LINx$ terminal. | –    | –    | 2.0  | $\mu\text{s}$    |
| Snubber Capacitor                          | $C_S$      | Between $V_{CC}$ and COM. Use properly-rated film capacitor for voltage surge suppression.                                                                                                    | 0.01 | –    | 0.1  | $\mu\text{F}$    |
| Junction Temperature                       | $T_J$      |                                                                                                                                                                                               | –    | –    | 125  | $^\circ\text{C}$ |

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature,  $T_A$ , of  $25^\circ\text{C}$ , unless otherwise stated.

## Typical Application Diagram



## NOTE:

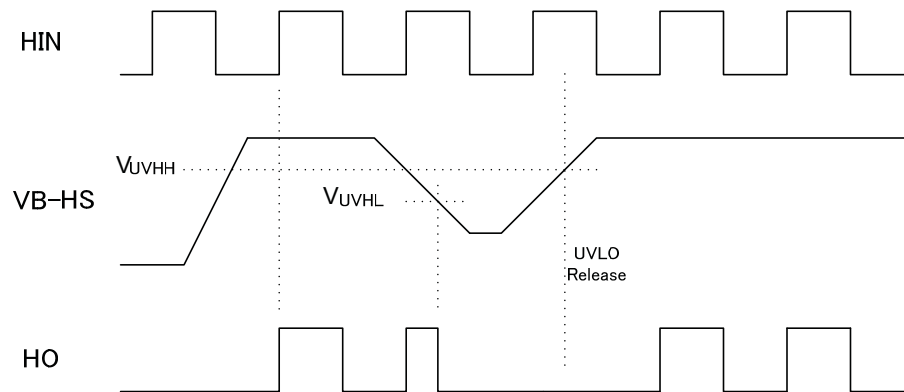
- All of the input pins are connected to GND with internal pull-down resistors rated at 100 k $\Omega$ , however, an external pull-down resistor may be required to secure stable condition of the inputs if high impedance conditions are applied to them.
- The external electrolytic capacitors should be placed as close to the IC as possible, in order to avoid malfunctions from external noise interference. Put a ceramic capacitor in parallel with the electrolytic capacitor if further reduction of noise susceptibility is necessary.

ELECTRICAL CHARACTERISTICS, valid at  $T_A=25^{\circ}\text{C}$ , unless otherwise noted

| Characteristics                                                | Symbol        | Conditions                                                                                                                        | Min  | Typ  | Max  | Units              |
|----------------------------------------------------------------|---------------|-----------------------------------------------------------------------------------------------------------------------------------|------|------|------|--------------------|
| Logic Supply Voltage                                           | $V_{CC}$      | Between VCC and COM                                                                                                               | 13.5 | 15   | 16.5 | V                  |
| Logic Supply Current                                           | $I_{CC}$      | $V_{CC} = 15\text{ V}$ , $V_{IN} = 5\text{ V}$                                                                                    | –    | 4    | 6    | mA                 |
| Input Voltage                                                  | $V_{IH}$      | $V_{CC} = 15\text{ V}$ , output on                                                                                                | –    | 2.0  | 2.5  | V                  |
|                                                                | $V_{IL}$      | $V_{CC} = 15\text{ V}$ , output off                                                                                               | 1.0  | 1.5  | –    | V                  |
| Input Voltage Hysteresis                                       | $V_{Ihys}$    | $V_{CC} = 15\text{ V}$                                                                                                            | –    | 0.5  | –    | V                  |
| Input Current                                                  | $I_{IH}$      | High side, $V_{CC} = 15\text{ V}$ , $V_{IN} = 5\text{ V}$                                                                         | –    | 50   | 100  | $\mu\text{A}$      |
|                                                                | $I_{IL}$      | Low side, $V_{CC} = 15\text{ V}$ , $V_{IN} = 0\text{ V}$                                                                          | –    | –    | 2    | $\mu\text{A}$      |
| Undervoltage Lockout                                           | $V_{UVHL}$    | High side, between VB and U, V, or W                                                                                              | 9.0  | 10.0 | 11.0 | V                  |
|                                                                | $V_{UVHH}$    |                                                                                                                                   | 9.5  | 10.5 | 11.5 | V                  |
|                                                                | $V_{UVHhys}$  | High side, hysteresis                                                                                                             | –    | 0.5  | –    | V                  |
|                                                                | $V_{UVLL}$    | Low side, between VCC and COM                                                                                                     | 10.0 | 11.0 | 12.0 | V                  |
|                                                                | $V_{UVLH}$    |                                                                                                                                   | 10.5 | 11.5 | 12.5 | V                  |
|                                                                | $V_{UVLhys}$  | Low side, hysteresis                                                                                                              | –    | 0.5  | –    | V                  |
| – $V_O$ for Output Voltage <sup>1</sup>                        | – $V_O$       | Between U, V, or W and COM                                                                                                        | –5   | –    | –    | V                  |
| LS Negative Surge Voltage <sup>2</sup>                         | $V_{LS}$      | Between LS1, LS2, or LS3 and COM                                                                                                  | –5   | –    | 5    | V                  |
| FO Terminal Output Voltage                                     | $V_{FOL}$     | $V_{CC} = 15\text{ V}$ , $I_{FO} = -1\text{ mA}$                                                                                  | 0    | –    | 1.0  | V                  |
|                                                                | $V_{FOH}$     | $V_{CC} = 15\text{ V}$ , $I_{FO} = -1.6\text{ mA}$                                                                                | 4.0  | –    | 5.5  | V                  |
| Overtemperature Detection Activating and Releasing Temperature | $T_{TDH}$     | $V_{CC} = 15\text{ V}$ , no heatsink, $I_{REG} = 0\text{ mA}$                                                                     | 135  | 150  | 165  | $^{\circ}\text{C}$ |
|                                                                | $T_{TDL}$     |                                                                                                                                   | 105  | 120  | 135  | $^{\circ}\text{C}$ |
|                                                                | $T_{TDhys}$   |                                                                                                                                   | –    | 30   | –    | $^{\circ}\text{C}$ |
| Output Voltage for Regulator                                   | $V_{REG}$     | $I_{REG} = 0$ to 35 mA                                                                                                            | 6.75 | 7.5  | 8.25 | V                  |
| IGBT Breakdown Voltage                                         | $V_{CES}$     | $V_{CC} = 15\text{ V}$ , $I_C = 1\text{ mA}$ , $V_{IN} = 0\text{ V}$                                                              | 600  | –    | –    | V                  |
| IGBT Leakage Current                                           | $I_{CES}$     | $V_{CC} = 15\text{ V}$ , $V_{CE} = 600\text{ V}$ , $V_{IN} = 0\text{ V}$                                                          | –    | –    | 1    | mA                 |
| IGBT Saturation Voltage                                        | $V_{CE(sat)}$ | $V_{CC} = 15\text{ V}$ , $I_C = 3\text{ A}$ , $V_{IN} = 5\text{ V}$                                                               | –    | 1.75 | 2.1  | V                  |
| Diode Forward Voltage                                          | $V_F$         | $V_{CC} = 15\text{ V}$ , $I_F = 3\text{ A}$ , $V_{IN} = 0\text{ V}$                                                               | –    | 1.65 | 2.0  | V                  |
| Diode Recovery Time                                            | $t_{rr}$      | $I_F = 3\text{ A}$ , $di/dt = 100\text{ A}/\mu\text{s}$                                                                           | –    | 50   | –    | ns                 |
| Switching Time, High Side                                      | $t_{dH(on)}$  | $V_{BB} = 300\text{ V}$ , $V_{CC} = 15\text{ V}$ , $I_C = 3\text{ A}$ , $0\text{ V} \leq V_{IN} \leq 5\text{ V}$ , inductive load | –    | 315  | –    | ns                 |
|                                                                | $t_{rH}$      |                                                                                                                                   | –    | 50   | –    | ns                 |
|                                                                | $t_{dH(off)}$ |                                                                                                                                   | –    | 375  | –    | ns                 |
|                                                                | $t_{fH}$      |                                                                                                                                   | –    | 165  | –    | ns                 |
| Switching Time, Low Side                                       | $t_{dL(on)}$  |                                                                                                                                   | –    | 325  | –    | ns                 |
|                                                                | $t_{rL}$      |                                                                                                                                   | –    | 60   | –    | ns                 |
|                                                                | $t_{dL(off)}$ |                                                                                                                                   | –    | 400  | –    | ns                 |
|                                                                | $t_{fL}$      |                                                                                                                                   | –    | 165  | –    | ns                 |

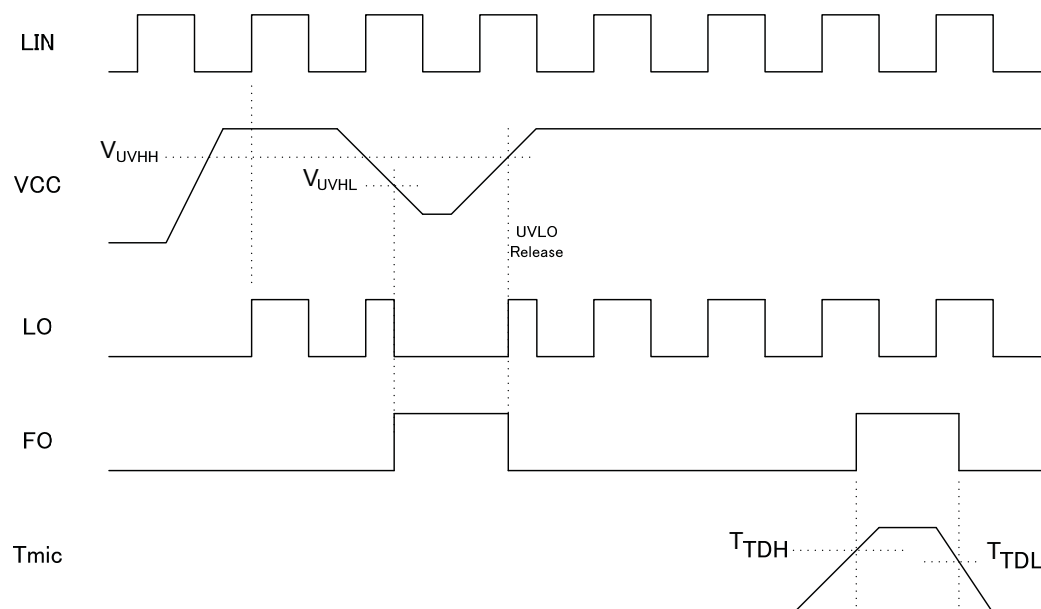
<sup>1</sup>Indicates normal operating range for the high-side driver IC.<sup>2</sup>Indicates the allowable range assuming any transient surge <1  $\mu\text{s}$ .

High-Side Driver Input/Output Timing Diagrams

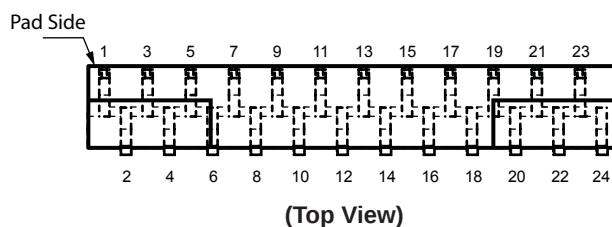


- High-side turn-on at next rising edge on HIN signal after UVLO release.
- FO output state does not change at high-side UVLO.

Low-Side Driver Input/Output Timing Diagrams



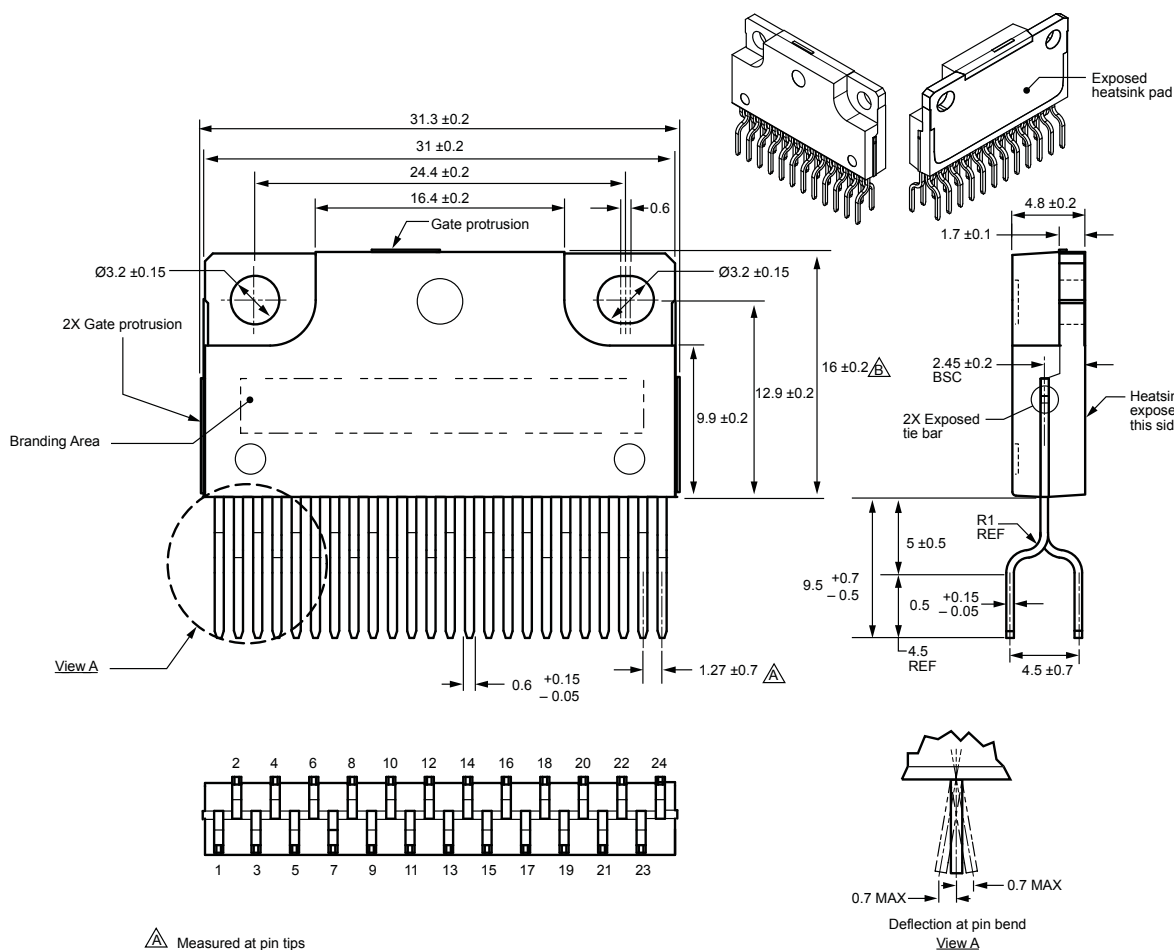
- Low-side turn-on in accordance with LIN signal level after UVLO release.
- FO output state goes high at low-side UVLO.

**Pin-out Diagram****Terminal List Table**

| Number | Name | Function                                               |
|--------|------|--------------------------------------------------------|
| 1      | U    | Output of U phase                                      |
| 2      | VB1  | High side bootstrap terminal (U phase)                 |
| 3      | VB2  | High side bootstrap terminal (V phase)                 |
| 4      | VB3  | High side bootstrap terminal (W phase)                 |
| 5      | VCC1 | High side logic supply voltage                         |
| 6      | COM1 | High side logic GND terminal                           |
| 7      | HIN3 | High side input terminal (W phase)                     |
| 8      | HIN2 | High side input terminal (V phase)                     |
| 9      | HIN1 | High side input terminal (U phase)                     |
| 10     | VBB1 | Main supply voltage 1 (connect to VBB2 externally)     |
| 11     | VBB2 | Main supply voltage 2 (connect to VBB1 externally)     |
| 12     | W1   | Output of W phase (connect to W2 externally)           |
| 13     | V    | Output of V phase                                      |
| 14     | W2   | Output of W phase (connect to W1 externally)           |
| 15     | LS3  | Low side emitter terminal (W phase)                    |
| 16     | VREG | Internal regulator output terminal                     |
| 17     | LS2  | Low side emitter terminal (V phase)                    |
| 18     | LIN3 | Low side input terminal (W phase)                      |
| 19     | LIN2 | Low side input terminal (V phase)                      |
| 20     | LIN1 | Low side input terminal (U phase)                      |
| 21     | COM2 | Low side GND terminal                                  |
| 22     | FO   | Overtemperature detection fault-signal output terminal |
| 23     | VCC2 | Low side logic supply voltage                          |
| 24     | LS1  | Low side source terminal (U phase)                     |

### Package Outline Drawing Leadform 2171

Dual rows, 24 alternating pins; vertical case mounting; pin #1 on pad side



△ Measured at pin tips  
△ To case top

Leadform: 2171  
Terminal core material: Cu  
Terminal plating: Ni  
Recommended attachment: Solder dip (Sn-Ag-Cu)

Dimensions in millimeters  
Branding codes (exact appearance at manufacturer discretion):  
1st line, type: SLA6845M

2nd line, lot: YMDDZ  
Where: Y is the last digit of the year of manufacture  
M is the month (1 to 9, O, N, D)  
DD is the date  
Z represents the version, SLA6845MZ



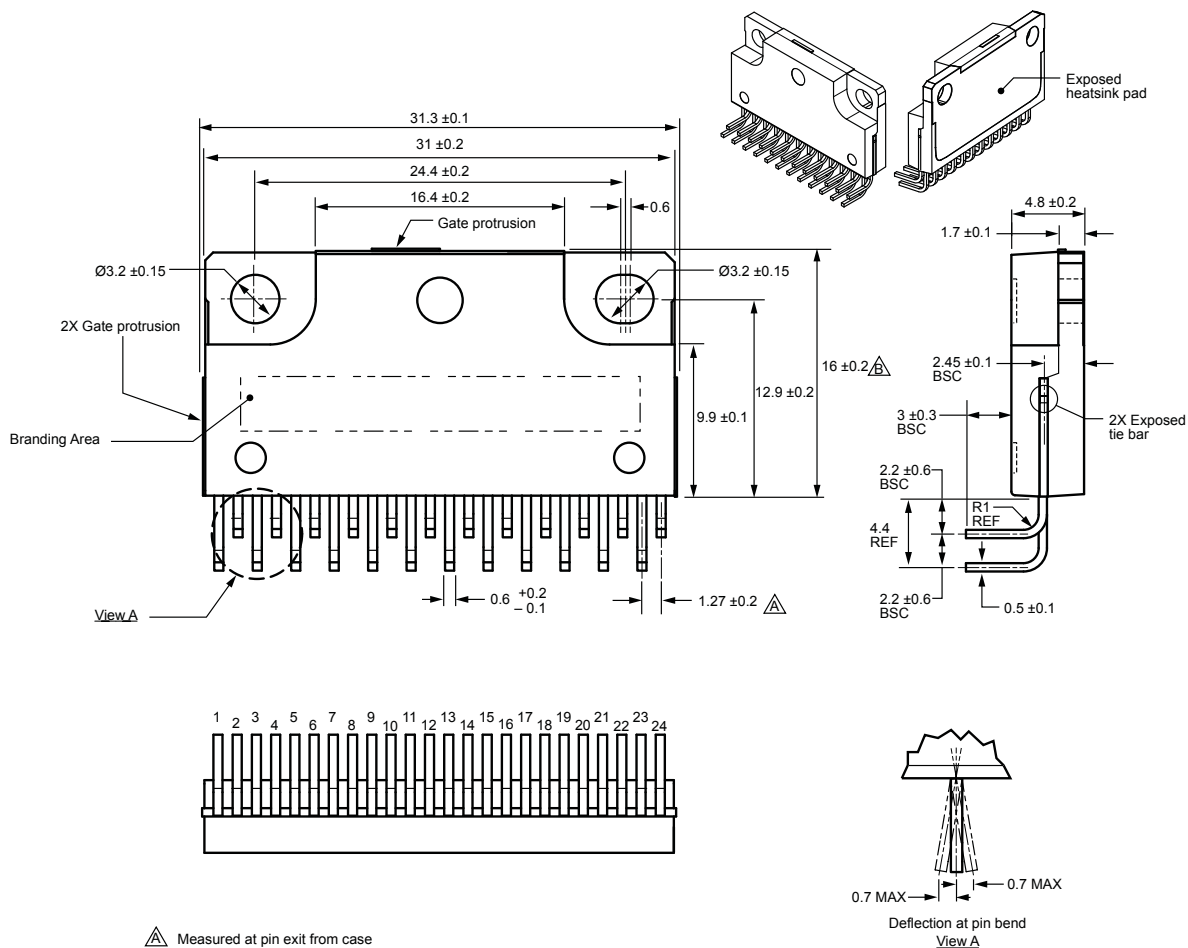
Leadframe plating Pb-free. Device composition complies with the RoHS directive.

Appearance: The body shall be clean and shall not bear any stain, rust or flaw.  
Marking: The type number and lot number shall be clearly marked.

## Package Outline Drawing

### Leadform 2175

Dual rows, 24 alternating pins; pins bent 90° for horizontal case mounting; pin #1 in outer row



Leadform: 2175

Terminal core material: Cu

Terminal plating: Ni

Recommended attachment: Solder dip (Sn-Ag-Cu)

Dimensions in millimeters

Branding codes (exact appearance at manufacturer discretion):

1st line, type: SLA6845M

2nd line, lot: YMDDZ

Where: Y is the last digit of the year of manufacture

M is the month (1 to 9, O, N, D)

DD is the date

Z represents the version, SLA6845MZ



Leadframe plating Pb-free. Device composition complies with the RoHS directive.

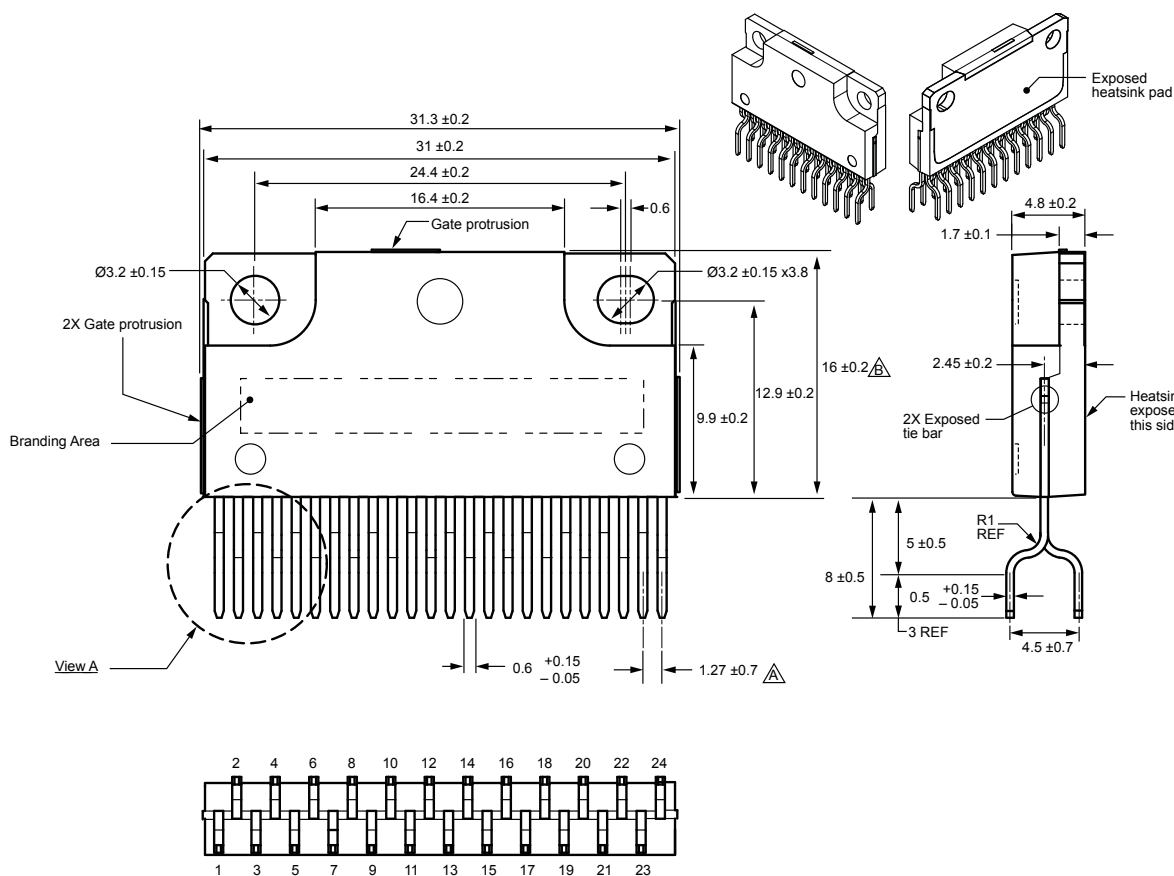
Appearance: The body shall be clean and shall not bear any stain, rust or flaw.

Marking: The type number and lot number shall be clearly marked.

## Package Outline Drawing

### Leadform 2178

Dual rows, 24 alternating pins; vertical case mounting; pin #1 on pad side



 Measured at pin tips  
 To case top

Leadform: 2178  
Terminal core material: Cu  
Terminal plating: Ni  
Recommended attachment: Solder dip (Sn-Ag-Cu)

Dimensions in millimeters

Branding codes (exact appearance at manufacturer discretion):  
1st line, type: SLA6845M

2nd line, lot: YMDDZ  
Where: Y is the last digit of the year of manufacture  
M is the month (1 to 9, O, N, D)  
DD is the date  
Z represents the version, SLA6845MZ

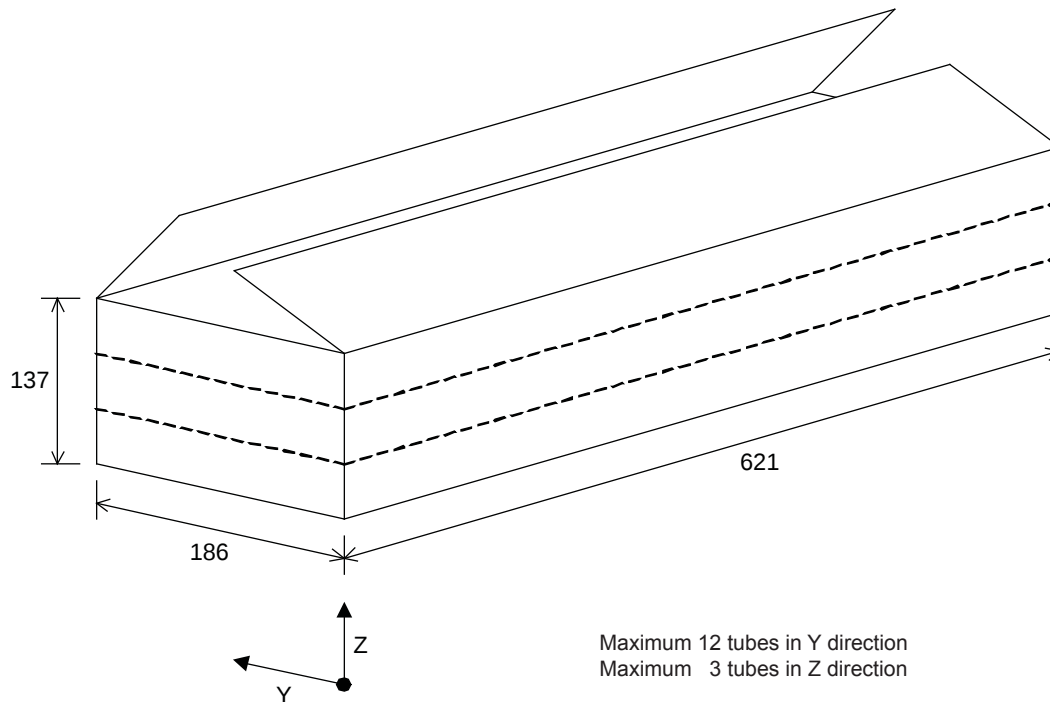
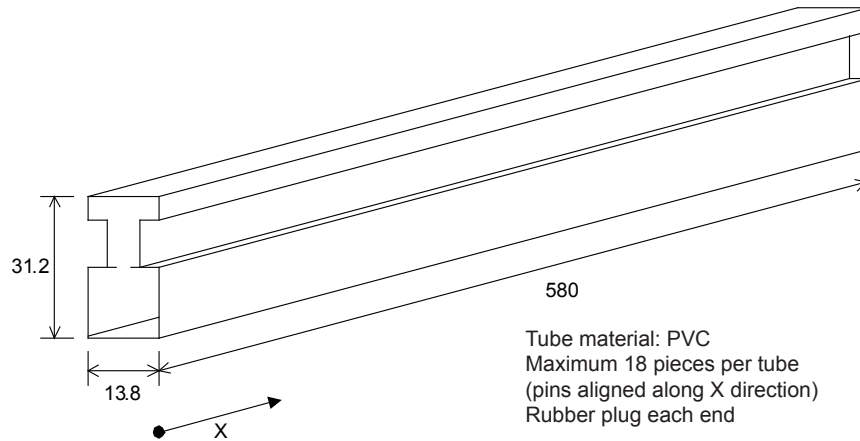


*Leadframe plating Pb-free. Device composition complies with the RoHS directive.*

Appearance: The body shall be clean and shall not bear any stain, rust or flaw.  
Marking: The type number and lot number shall be clearly marked.

**Packing Specification****Leadform 2171**

Dimensions in millimeters



Maximum pieces per carton:

18 pieces per tube

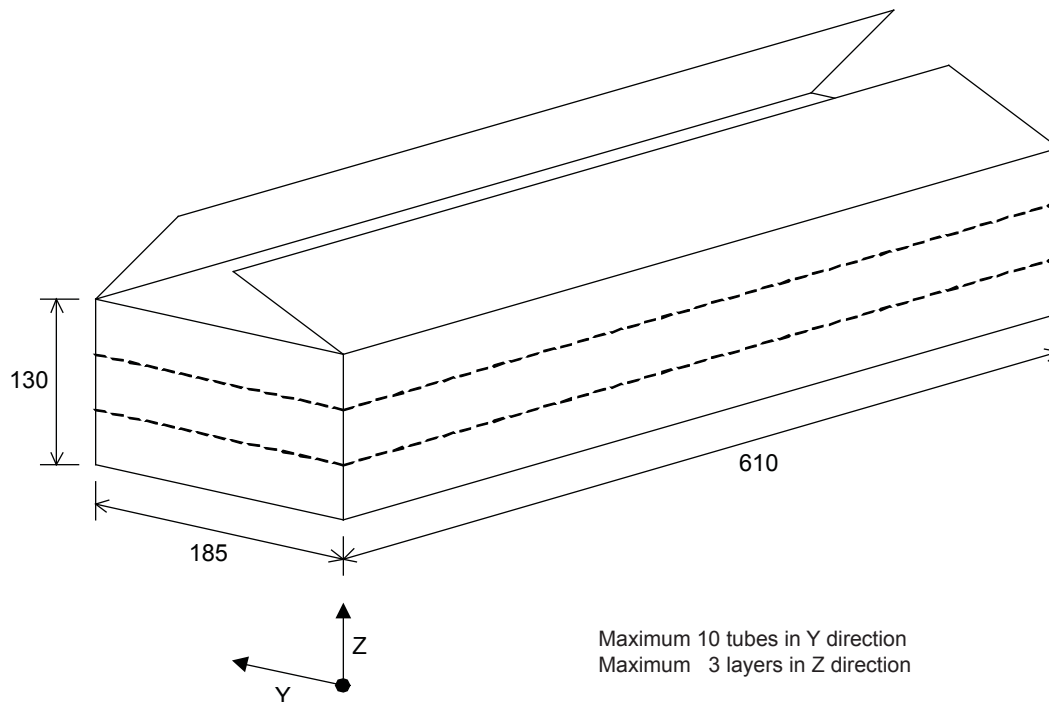
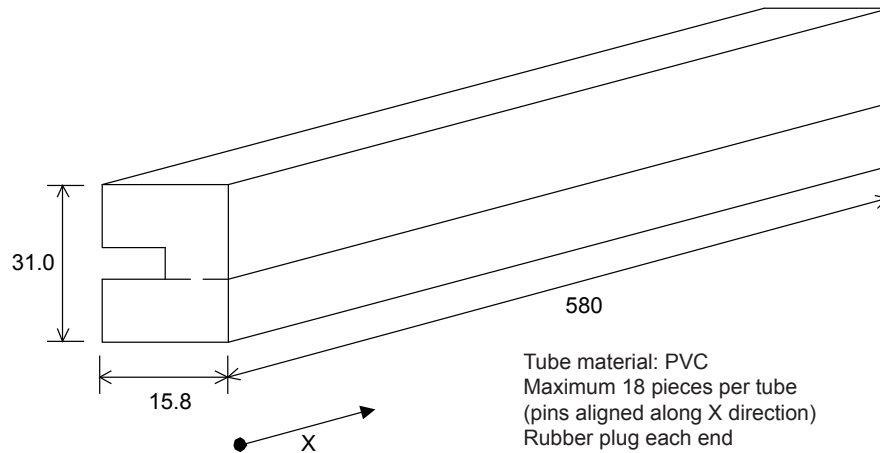
12 tubes per layer

x 3 layers of tubes

648 pieces per carton

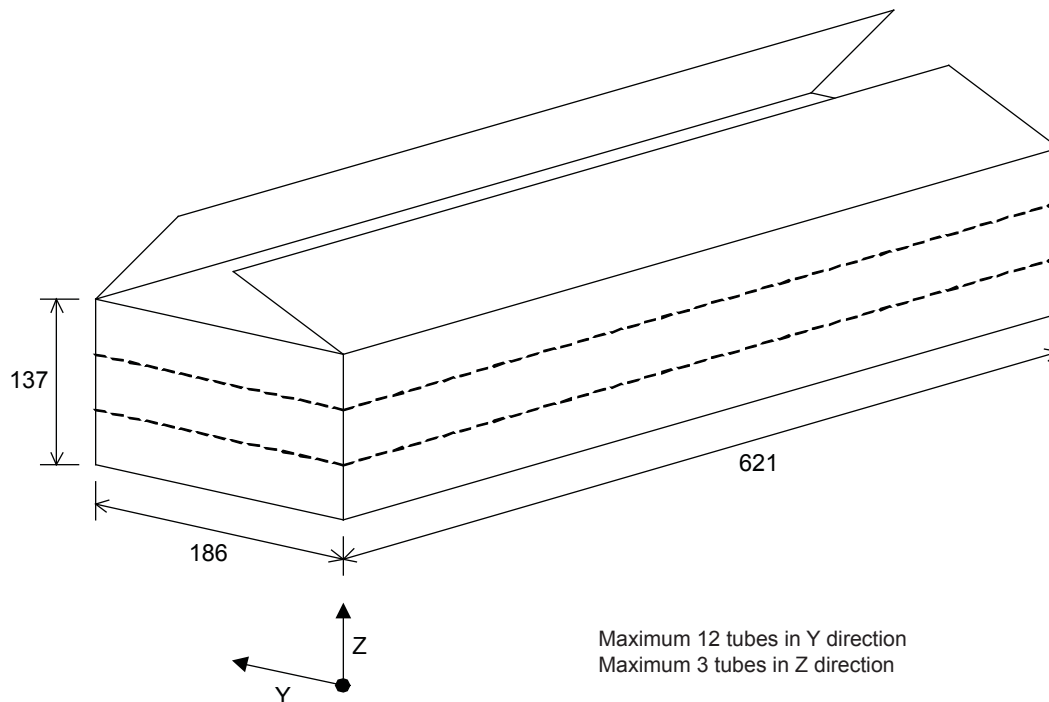
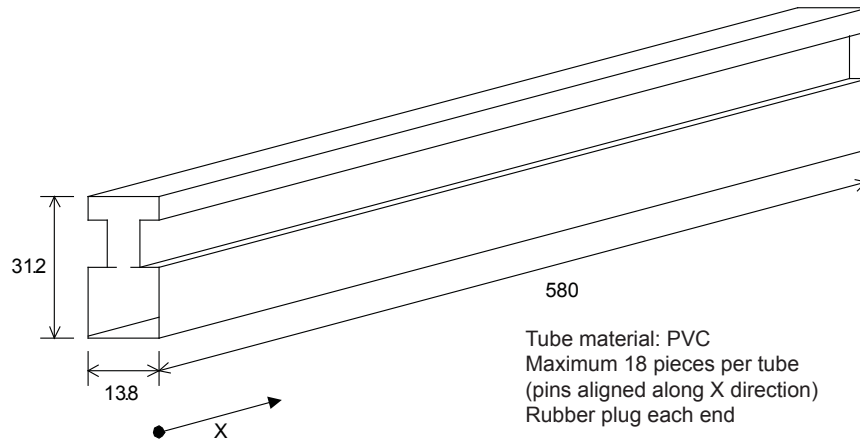
**Packing Specification****Leadform 2175**

Dimensions in millimeters



**Packing Specification****Leadform 2178**

Dimensions in millimeters



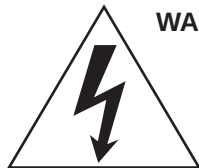
Maximum pieces per carton:

18 pieces per tube

12 tubes per layer

x 3 layers of tubes

648 pieces per carton



**WARNING** — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

#### Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of products that have been stored for a long time.

#### Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between adjacent products, and shorts to the heatsink.

#### Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting this product on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce stress.
- Volatile-type silicone greases may permeate the product and produce cracks after long periods of time, resulting in reduced heat radiation effect, and possibly shortening the lifetime of the product.
- Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

| Type   | Suppliers                             |
|--------|---------------------------------------|
| G746   | Shin-Etsu Chemical Co., Ltd.          |
| YG6260 | Momentive Performance Materials, Inc. |
| SC102  | Dow Corning Toray Silicone Co., Ltd.  |

#### Heatsink Mounting Method

**Torque When Tightening Mounting Screws.** The recommended tightening torque for this product package type is: 58.8 to 78.4 N•cm (6.0 to 8.0 kgf•cm).

#### Soldering

- When soldering the products, please be sure to minimize the working time, within the following limits:  
 $260 \pm 5^{\circ}\text{C}$  10 s  
 $380 \pm 5^{\circ}\text{C}$  5 s
- Soldering iron should be at a distance of at least 1.5 mm from the body of the products

#### Electrostatic Discharge

- When handling the products, operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance to ground to prevent shock hazard.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in our shipping containers or conductive containers, or be wrapped in aluminum foil.

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